

Product Summary (@T_A = +25°C)

P _{PK}	I _{FSM} (A)	V _{RWM} (V)	PM _(AV)
6600W	700	10 to 43	8W

Features and Benefits

- 6600W Peak Pulse Power Dissipation
- T_J = +175°C Capability Suitable for High Reliability and Automotive Requirement
- High Current Capability
- Excellent High-Temperature Stability
- Meets ISO7637-2 Surge Capability
- Meets ISO16750-2 Surge Specification
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The DM8W10AQ-DM8W43AQ are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**
<https://www.diodes.com/quality/product-definitions/>

Description and Applications

The DM8W10AQ-DM8W43AQ are suitable to protect sensitive automotive circuits against surges defined in ISO7637-2 and against load-dump surge according to ISO16750-2.

The devices meet compliance with the following standards:

- ISO 16750-2, Pulse A and Pulse B
- ISO 7637-2 (Note 5)
Pulse 1, Pulse 2a, Pulse 3a, Pulse 3b

Mechanical Data

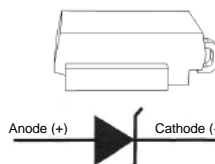
- Package: DO-218 (Type E)
- Package Material: Molded Plastic.
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead-Free Plating (Matte Tin Finish).
Solderable per MIL-STD-202, Method 208 (E3)
- Polarity Indicator: Heatsink is Anode
- Weight: 2.74 grams (Approximate)

DO-218 (Type E)



Top View

Polarity: Heatsink is Anode



Pin Information

Ordering Information (Note 4)

Part Number	Qualification	Package	Packing	
			Qty.	Carrier
DM8WxxAQ-13	Automotive	DO-218 (Type E)	750	Tape & Reel

*x = Device Voltage, e.g., DM8W18AQ-13

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.
 5. Not applicable to parts with stand-off voltage lower than the average battery voltage (13.5V).

Marking Information



M8WxxA = Product Type Marking Code (i.e. M8W18A for DM8W18AQ-13)
 ⌋|| = Manufacturers' Code Marking
 aa: Wafer source code
 y: Year (M = 2022)
 m: Month (1 – C)
 d: Date (1 – V)
 cc: Lot serial number
 Bar Denotes Cathode Pin, Circle Denotes Anode

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Peak Pulse Power Dissipation (Non Repetitive Current Pulse Derated above T _A = +25°C) (Note 6)	P _{PK}	10/1000μs Waveform	6600
		10/10000μs Waveform	5200
Peak Forward Surge Current, 8.3ms Single Half Sine-Wave Superimposed on Rated Load (Note 7)	I _{FSM}	700	A
Steady State Power Dissipation @ T _C = +25°C	PM _(AV)	8.0	W

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Case	R _{θJC}	0.9	°C/W
Operating Temperature Range	T _J	-55 to +175	°C
Storage Temperature Range	T _{STG}	-55 to +175	°C

Notes: 6. Valid provided that terminals are kept at ambient temperature.
 7. Measured on 8.3ms single half sine-wave or equivalent square wave. Duty cycle = 4 pulses per minute maximum.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Part Number	Reverse Standoff Voltage	Breakdown Voltage V _{BR} @ I _T (Note 8)		Test Current	Max. Reverse Leakage @ V _{RWM} (Note 10)	Max. Clamping Voltage @ I _{pp}	Max. Peak Pulse Current I _{pp} at 10/1000μs (Note 9)	Maximum Leakage at V _{WM} T _J = +175°C
	V _{RWM} (V)	Min (V)	Max (V)	I _T (mA)	I _R (μA)	V _C (V)	(A)	I _D (μA)
DM8W10AQ	10	11.1	12.3	5	15	17.0	388	250
DM8W11AQ	11	12.2	13.5	5	10	18.2	363	150
DM8W12AQ	12	13.3	14.7	5	10	19.9	332	150
DM8W13AQ	13	14.4	15.9	5	10	21.5	307	150
DM8W14AQ	14	15.6	17.2	5	10	23.2	284	150
DM8W15AQ	15	16.7	18.5	5	10	24.4	270	150
DM8W16AQ	16	17.8	19.7	5	10	26.0	254	150
DM8W17AQ	17	18.9	20.9	5	10	27.6	239	150
DM8W18AQ	18	20.0	22.1	5	10	29.2	226	150
DM8W20AQ	20	22.2	24.5	5	10	32.4	204	150
DM8W22AQ	22	24.4	26.9	5	10	35.5	186	150
DM8W24AQ	24	26.7	29.5	5	10	38.9	170	150
DM8W26AQ	26	28.9	31.9	5	10	42.1	157	150
DM8W28AQ	28	31.1	34.4	5	10	45.4	145	150
DM8W30AQ	30	33.3	36.8	5	10	48.4	136	150
DM8W33AQ	33	36.7	40.6	5	10	53.3	124	150
DM8W36AQ	36	40.0	44.2	5	10	58.1	114	150
DM8W40AQ	40	44.4	49.1	5	10	64.5	102	150
DM8W43AQ	43	47.8	52.8	5	10	69.4	95.1	150

Notes: 8. V_{BR} measured with I_T current pulse = 10ms to 15ms.
 9. Per 10 × 1000μs waveform. See Figure 3.
 10. Short duration pulse test used so as to minimize the self-heating effect.

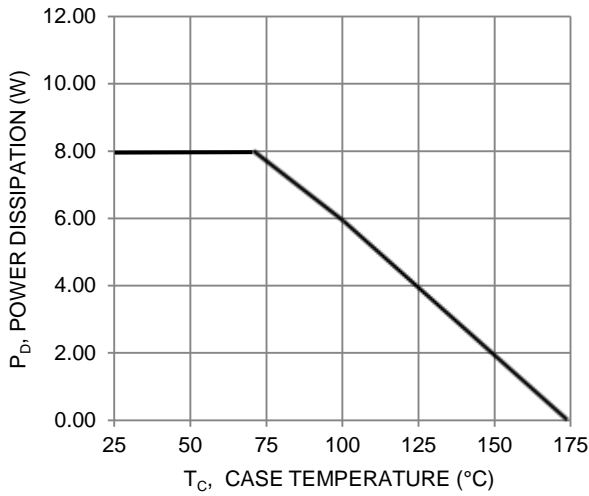


Fig. 1 Power Derating Curve

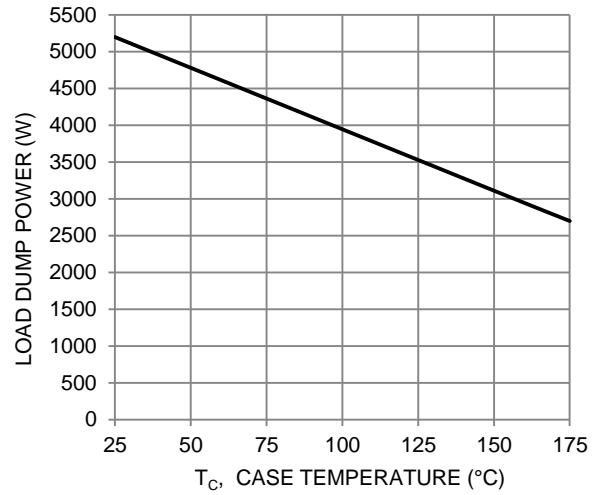


Fig. 2 Load Dump Power Characteristics (10ms Exponential Waveform)

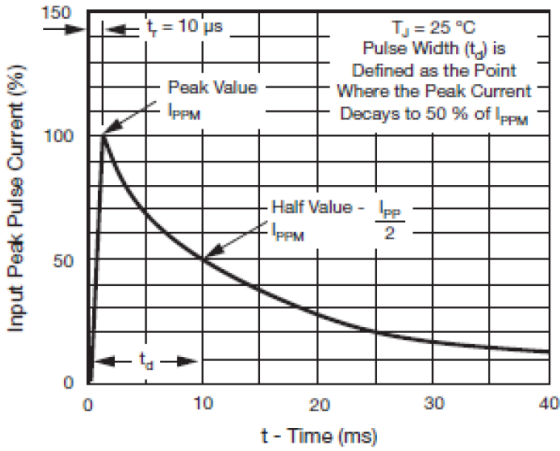


Fig. 3 - Pulse Waveform

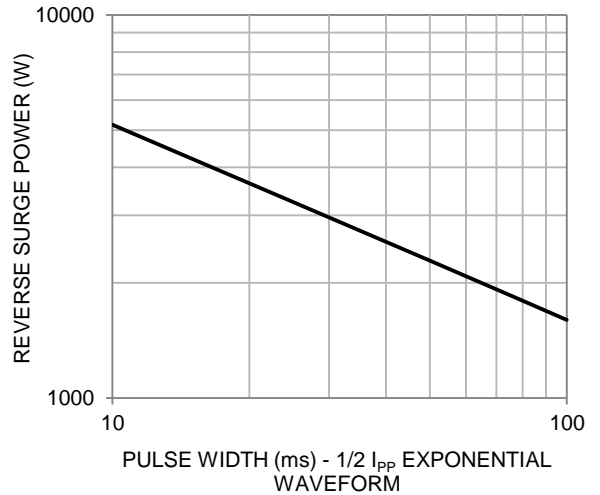


Fig. 4 Reverse Power Capability

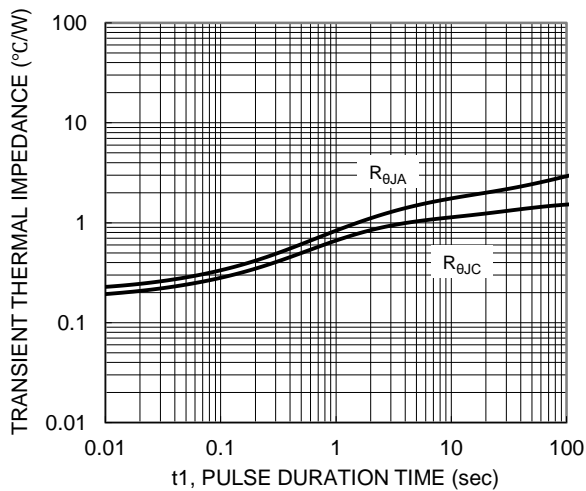


Fig. 5 Typical Transient Thermal Impedance

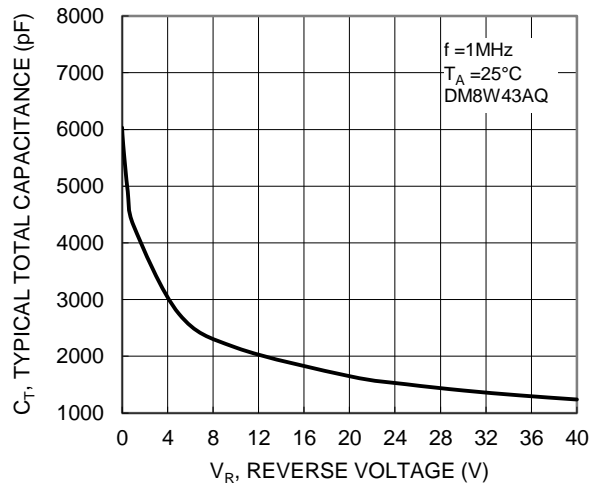
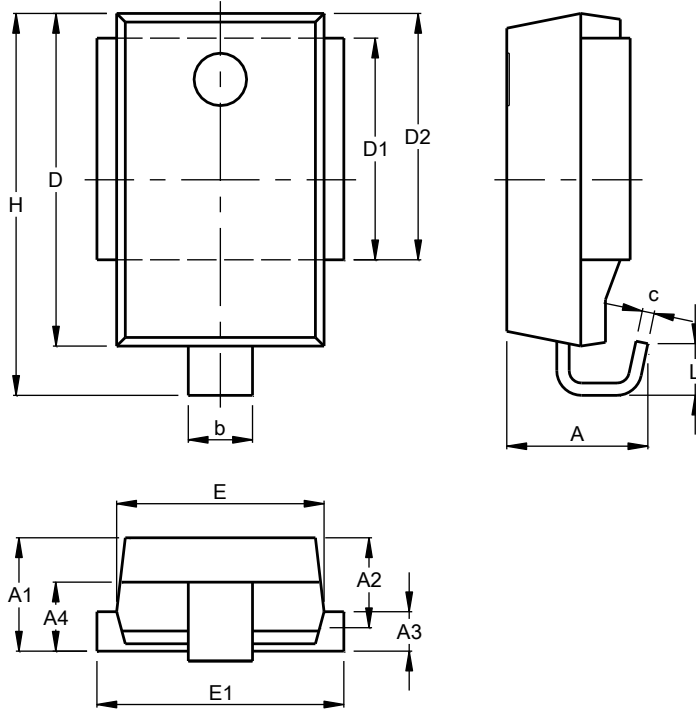


Fig. 6 Typical Total Capacitance (DM8W43AQ Only)

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

DO-218 (Type E)

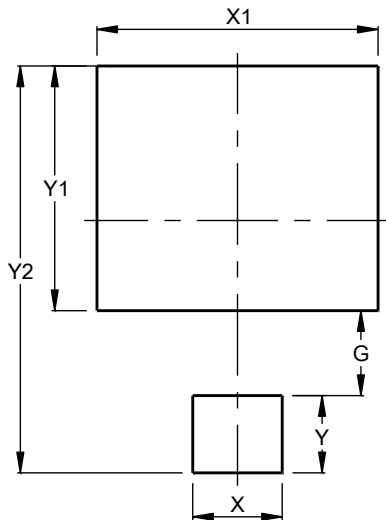


DO-218 (Type E)			
Dim	Min	Max	Typ
A	4.70	5.70	--
A1	4.70	5.25	5.00
A2	3.45	4.26	3.95
A3	1.70	2.50	2.00
A4	2.58	3.55	3.10
b	2.30	3.00	--
c	0.45	0.90	--
D	13.20	13.80	13.50
D1	8.70	9.30	9.00
D2	9.70	10.30	10.00
E	8.20	8.80	8.50
E1	9.50	10.50	--
H	15.00	16.00	15.50
L	1.50	2.50	2.00
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

DO-218 (Type E)



Dimensions	Value (in mm)
G	3.30
X	3.50
X1	11.00
Y	3.00
Y1	9.50
Y2	15.80

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